6N137 OPTOCOUPLER/OPTOISOLATOR

SOOS003 D2918, JULY 1986

- Gallium Arsenide Phosphide LED Optically Coupled to Integrated Circuit Detector
- Compatible with TTL and LSTTL inputs
- Low Input Current Required to Turn Output On . . . 5 mA Max
- High-Voltage Electrical Insulation . . . 3000 V DC Min
- High-Speed Switching . . . 75 ns Max
- Plastic Dual-In-Line Package
- UL Recognized . . . File Number 65085

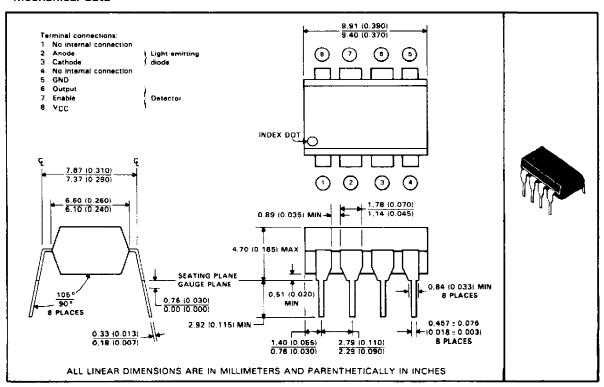
description

The 6N137 optocoupler is designed for use in high-speed digital interfacing applications that require high-voltage isolation between the input and output. Applications include line receivers, microprocessors or computer interface, digital programming of floating power supplies, motors, and other control systems.

The 6N137 high-speed optocoupler consists of a GaAsP light-emitting diode and an integrated light detector composed of a photodiode, a high-gain amplifier, and a Schottky-clamped open-collector output transistor. An input diode forward current of 5 milliamperes will switch the output transistor low, providing an on-state drive current of 13 milliamperes (eight 1.6-milliampere TTL loads). A TTL-compatible enable input is provided for applications that require output-transistor gating.

The 6N137 is characterized for operation over the temperature range of 0°C to 70°C.

*mechanical data



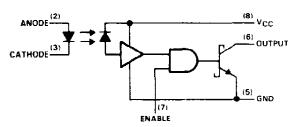
*JEDEC registered data. This data sheet contains all applicable registered data in effect at the time of publication.

Texas Instruments

FUNCTION TABLE

INPUT	ENABLE	OUTPUT
IF(on)	н	L
(F(off)	×	н
X	Ļ	н

logic diagram (positive logic)



*absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage, VCC
Peak forward input current (≤ 1 ms duration) (TI-guaranteed value)
(JEDEC-registered value)
Average forward input current (TI-guaranteed value)
(JEDEC-registered value)
Output current
Output power dissipation
Storage temperature range
Operating free-air temperature range
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds

^{*}JEDEC registered data

recommended operating conditions

,		MIN	NOM	MAX	UNIT
VCC	Output supply voltage (see Note 1)	4.5	5	5.5	V
VIH(EN)	High-level enable input voltage (see Note 2)	2		Vcc	V
VIL(EN)	Low-level enable input voltage	0		0.8	V
F(on)	Input forward current to turn output on	6.3		15	mA
IF(off)	Input forward current to turn output off	0		250	μА
JOL	Low-level (on-state) output current			13	mΑ
TA	Operating free-air temperature	Ö		70	°C

NOTES: 1. All voltage values are with respect to GND (pin 5).

^{2.} No external pullup is required at the enable input; an open circuit will establish the high level.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
•v _F	Input forward voltage	lp = 10 mA.	T _A = 25°C		1.6	1.75	V
αVF	Temperature coefficient of forward voltage	ŧϝ = 10 mA			- 1.8		mV/°C
*VBR	Input reverse breakdown voltage	IR = 10 μA,	T _A = 25°C	5			V
•vot	Low-level output voltage	VCC = 5.5 V. I _F = 5 mA,	, ,		0.23	0.6	٧
*Іон	High-level output current	V _{CC} = 5.5 V. V _(EN) = 2 V.	V _O = 5.5 V, I _F = 250 μA			250	μА
IH(EN)	High-level enable input current	V _{CC} = 5.5 V,	V _(EN) = 2 V		-0.2		mA
*ILIENI	Low-level enable input current	V _C C = 5.5 V.	$V_{(EN)} = 0.5 V$		- 0.5	- 2	mΑ
*Іссн	Supply current, high-level output	$V_{CC} = 5.5 \text{ V},$ $I_F = 0$	$V_{(EN)} = 0.5 V,$		10	15	mA
*ICCL	Supply current, law-level autput	V _{CC} = 5.5 V, I _F = 10 mA	V _(EN) = 0.5 V,		13	18	mA
*IIO	Input-output insulation leakage current	V _{IO} = 3000 V. T _A = 25°C. See Note 1				1	μΑ
710	Input-output resistance	V _{IO} = 500 V, See Note 1	Τ _Α = 25°C,		1012		Ω
C;	Input capacitance	Vr = 0.	f = 1 MHz		60		pF
Cio	Input-output capacitance	f = 1 MHz, See Note 1	T _A = 25°C.		0.6		pF

^{*}JEDEC registered data

[†] All typical values are at $V_{CC} = 5 \text{ V}$, $T_A = 25 ^{\circ}\text{C}$. NOTE 1: These parameters are measured between pins 2 and 3 shorted together and pins 5, 6, 7, and 8 shorted together.

switching characteristics at VCC = 5 V, TA = 25°C

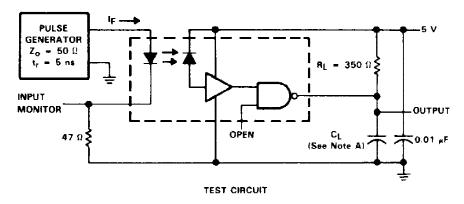
	PARAMETER	TEST CONDITIONS	MIN TYP	MAX	UNIT
*tPLH	Propagation delay time, low-to-high-level output, from LED input	$I_F = 7.5 \text{ mA}, R_L = 350 \Omega,$ $C_L = 15 \text{ pF}, \text{See Figure 1}$	42	75	ns
*tPHL	Propagation delay time, high-to-low level output, from LED input	$I_F = 7.5 \text{ mA}$, $R_L = 350 \Omega$, $C_L = 15 \text{ pF}$. See Figure 1	42	75	ns
^t PLH(EN)	Propagation delay time, low-to-high level output, from enable	$R_L = 7.5 \text{ mA}, R_L = 350 \Omega,$ $C_L = 15 \text{ pF}, See Figure 2}$	40		ns
tpHL(EN)	Propagation delay time, high-to-low-level output, from enable	$I_F = 7.5 \text{ mA}$, $R_L = 350 \Omega$, $C_L = 15 \text{ pF}$. See Figure 2	25		ns
t _t	Rise time	$I_F = 7.5 \text{ mA}, \qquad R_L = 350 \ \Omega,$ $C_L = 15 \text{ pF}$	20		ns
tf	Fall time	I_F = 7.5 mA. R_L = 350 Ω. C_L = 15 pF	30		ns
d√CM (H)	Common mode input transient immunity, high-level output	$\Delta V_{CM} = 10 \text{ V}, \text{i}_F = 0,$ $R_L = 350 \Omega,$ See Note 2 and Figure 3	50		V/μs
dVCM dt (L)	Common-mode input transient immunity, low-level output	$\Delta V_{CM} = -10 \text{ V. Ip} = 5 \text{ mA.}$ $R_L = 350 \text{ B.}$ See Note 2 and Figure 3	- 150		V/μs

*JEDEC registered data

NOTE 2: Common-mode input transient immunity, high-level output, is the maximum rate of rise of the common-mode input voltage that does not cause the output voltage to drop below 2 V. Common-mode input transient, low-level output, is the maximum rate of fall of the common-mode input voltage that does not cause the output voltage to rise above 0.8 V.



PARAMETER MEASUREMENT INFORMATION



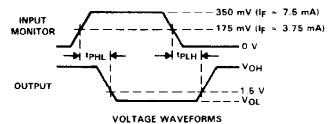
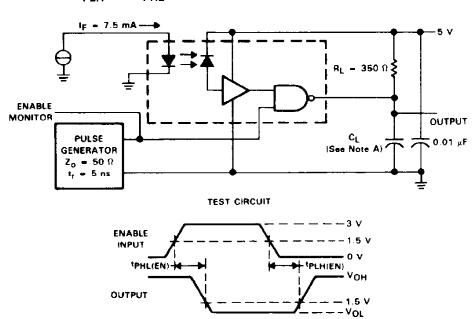


FIGURE 1. tPLH AND tPHL FROM LED INPUT TEST CIRCUIT AND WAVEFORMS

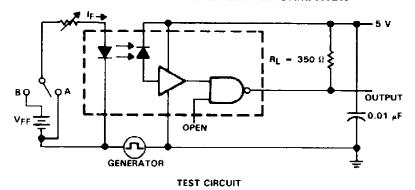


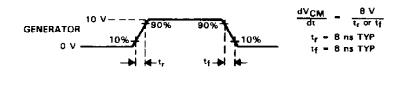
VOLTAGE WAVEFORMS
FIGURE 2. tplh(EN) AND tphl(EN) FROM ENABLE TEST CIRCUIT AND WAVEFORMS

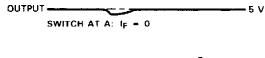
NOTE A: CL is approximately 15 pF, which includes probe and stray wiring capacitances.



PARAMETER MEASUREMENT INFORMATION







SWITCH AT B: IF = 5 mA

VOLTAGE WAVEFORMS

FIGURE 3. TRANSIENT IMMUNITY TEST CIRCUIT AND WAVEFORMS

TYPICAL APPLICATION INFORMATION

A ceramic capacitor (0.01 μ F to 0.1 μ F) should be connected between pins 8 and 5 to stabilize the high-gain amplifier. The total lead length between the capacitor and the optocoupler should not exceed 20 mm (0.8 inches). Failure to provide a bypass capacitor may result in impaired switching characteristics.

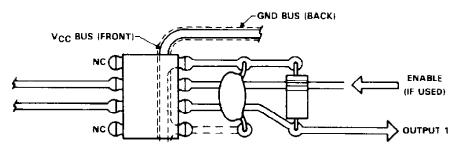


FIGURE 4. RECOMMENDED PRINTED CIRCUIT BOARD LAYOUT

TYPICAL CHARACTERISTICS

INPUT DIODE FORWARD CURRENT

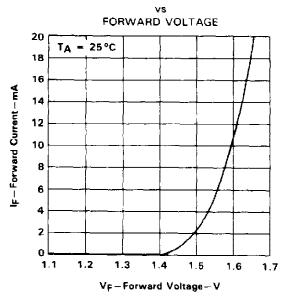


FIGURE 5

LOW-LEVEL OUTPUT VOLTAGE

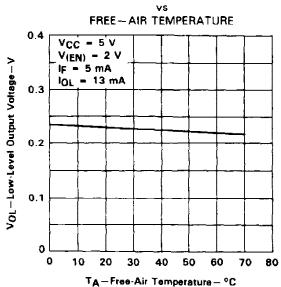


FIGURE 6

HIGH-LEVEL OUTPUT CURRENT

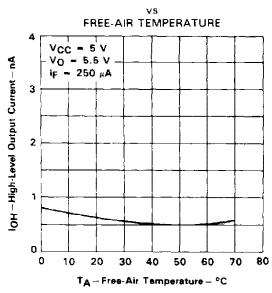


FIGURE 7

TYPICAL CHARACTERISTICS

PROPAGATION DELAY TIME FROM LED INPUT

vs PULSE FORWARD CURRENT

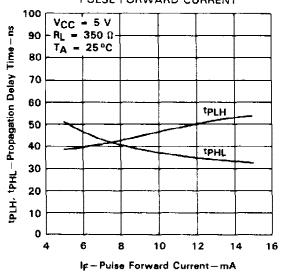


FIGURE 8

PROPAGATION DELAY TIME FROM LED INPUT

LOAD RESISTANCE

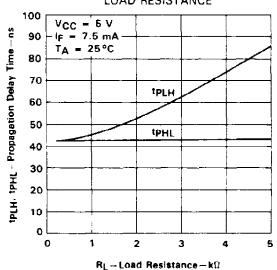


FIGURE 9

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